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| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|--|-----------------|----------------------|-------------------------|------------------|
| 10/611,585 | 07/01/2003 | Kent Oertle | 13693US02 | 5233 |
| 23446 | 7590 05/20/2005 | | EXAMINER | |
| | WS HELD & MALLO | LE, DON P | | |
| 500 WEST MADISON STREET SUITE 3400 CHICAGO, IL 60661 | | | ART UNIT | PAPER NUMBER |
| | | | | TALER NOMBER |
| | | | 2819 | |
| | | | DATE MAILED: 05/20/2005 | |

Please find below and/or attached an Office communication concerning this application or proceeding.

| | Application No. | Applicant(s) | |
|---|--|--|-----------|
| | 10/611,585 | OERTLE ET AL. | 1500 |
| Office Action Summary | Examiner | Art Unit | |
| | Don P. Le | 2819 | |
| The MAILING DATE of this communication app Period for Reply | pears on the cover sheet with the | correspondence addres | SS |
| A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). | 36(a). In no event, however, may a reply be ting within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE | mely filed ys will be considered timely. the mailing date of this commu ED (35 U.S.C. § 133). | nication. |
| Status | | | |
| 1) Responsive to communication(s) filed on 4/22/ | <u>′05</u> . | | |
| 2a) ☐ This action is FINAL . 2b) ☑ This | action is non-final. | | |
| 3) Since this application is in condition for alloward closed in accordance with the practice under E | | | rits is |
| Disposition of Claims | | | |
| 4) ☐ Claim(s) 1-6,9 and 12-16 is/are pending in the 4a) Of the above claim(s) is/are withdray 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-6,9 and 12-16 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/o | wn from consideration. | | |
| Application Papers | | | |
| 9) The specification is objected to by the Examine | r. · | | |
| 10)☐ The drawing(s) filed on is/are: a)☐ acc | epted or b) objected to by the | Examiner. | |
| Applicant may not request that any objection to the | drawing(s) be held in abeyance. Se | e 37 CFR 1.85(a). | |
| Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex | | | |
| Priority under 35 U.S.C. § 119 | | | |
| 12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list | s have been received. s have been received in Applicati ity documents have been receive u (PCT Rule 17.2(a)). | ion No ed in this National Stag | je |
| Attachment(s) | _ | | |
| 1) X Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) | 4) 🔲 Interview Summary Paper No(s)/Mail Da | | |
| Paper No(s)/Mail Date | | Patent Application (PTO-152 |) |

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Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (a) the invention was known or used by others in this country, or patented or described in a printed publication in this or a foreign country, before the invention thereof by the applicant for a patent.
- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1-6, 9 and 12-16 are rejected under 35 U.S.C. 102(b) as being anticipated by Hung et al. (US 6,018,257).
- With respect to claim 1, figure 9 of Hung discloses a circuit (212) coupled to an output device (104), the circuit comprising at least one transistor device comprising at least one p-channel device (506'), said at least one transistor device adapted to limit a duration of a high voltage across the output device thereby reducing hot carrier injection stress across-the output device (see abstract, prevent damage due to high voltage, high voltage causes hot carrier injection stress).
- 4. With respect to claim 2, figure 9 of Hung discloses two stacked transistor devices (102, 202) coupled to the output device.
- 5. With respect to claim 3, figure 9 of Hung discloses the at least one p-channel device (202) is coupled to the output device.
- 6. With respect to claim 4, figure 9 of Hung discloses the two stacked transistor devices comprise two stacked p-channel (102, 202) devices coupled to the output device.
- 7. With respect to claim 5, figure 9 of Hung discloses the output device comprises at least one n-channel output transistor (104).

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8. With respect to claim 6, figure 9 of Hung discloses the output device comprises two

stacked n-channel output transistors (104, 204).

9. With respect to claim 9, figure 9 of Hung teaches an integrated circuit comprising:

an IO PAD (coupled to OUTPUT);

an output circuit coupled to at least said IO PAD (figure 9); and

a stress circuit comprising at least one p-channel transistor (506'), said stress circuit

coupled to at least said output circuit and said IO PAD and adapted to limit a duration of a high

voltage across said output circuit when said output circuit is enabled, thereby reducing stress on

said output circuit.

10. With respect to claim 12, figure 9 of Hung discloses the at least one p-channel transistor

comprises two slacked p-channel transistor (502', 506').

11. With respect to claim 13, figure 9 of Hung discloses said output circuit comprises at least

one output transistor (104).

12. With respect to claim 14, figure 9 of Hung discloses the at least one output transistor

comprises an n-channel transistor (104).

13. With respect to claim 15, figure 9 of Hung discloses the at least one output transistor

comprises two stacked n-channel transistors (104, 204).

14. With respect to claim 16, the method therein is inherent in the apparatus of Hung as

shown in the above rejections.

Response to Arguments

15. Applicant's arguments with respect to claims 1-6, 9 and 12-16 have been considered but

are moot in view of the new ground(s) of rejection.

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16. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Don P. Le whose telephone number is 571-272-1806. The examiner can normally be reached on 7AM - 5PM:

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael J. Tokar can be reached on 571-272-1812. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

5/18/2005

DON LE PRIMARY EXAMBJER